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December 2015



BSS123W — N-Channel Logic Level Enhancement Mode Field Effect Transistor

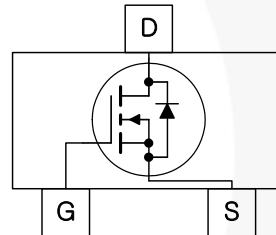
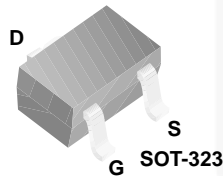
BSS123W N-Channel Logic Level Enhancement Mode Field Effect Transistor

Features

- 0.17 A, 100 V, $R_{DS(ON)} = 6 \Omega$ at $V_{GS} = 10 \text{ V}$
 $R_{DS(ON)} = 10 \Omega$ at $V_{GS} = 4.5 \text{ V}$
- High Density Cell Design for Low $R_{DS(ON)}$
- Rugged and Reliable
- Ultra Small Surface Mount Package
- Very Low Capacitance
- Fast Switching Speed
- Lead Free / RoHS Compliant

Description

This N-channel enhancement mode field effect transistor is produced using high cell density, trench MOSFET technology. This product minimizes on-state resistance while providing rugged, reliable and fast switching performance. This product is particularly suited for low-voltage, low-current applications such as small servo motor control, power MOSFET gate drivers, logic level transistor, high speed line drivers, power management/power supply and switching applications.



Ordering Information

| Part Number | Marking | Package | Packing Method |
|-------------|---------|------------|----------------|
| BSS123W | SA | SOT-323 3L | Tape and Reel |

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.

| Symbol | Parameter | Value | Unit |
|----------------|---|-------------|------------------|
| V_{DSS} | Drain-Source Voltage | 100 | V |
| V_{DGR} | Drain-Gate Voltage $R_{GS} \leq 20 \text{ k}\Omega$ | 100 | V |
| V_{GSS} | Gate-Source Voltage | ± 20 | V |
| I_D | Drain Current | Continuous | 0.17 |
| | | Pulsed | 0.68 |
| T_J, T_{STG} | Operating and Storage Temperature Range | -55 to +150 | $^\circ\text{C}$ |

Thermal Characteristics

Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.

| Symbol | Parameter | Value | Unit |
|-----------------|--|-------|----------------------|
| P_D | Total Power Dissipation | 200 | mW |
| | Derate Above 25°C | 1.6 | mW/ $^\circ\text{C}$ |
| $R_{\theta JA}$ | Thermal Resistance, Junction-to-Ambient ⁽¹⁾ | 625 | $^\circ\text{C/W}$ |

Note:

1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch. Minimum land pad size.

Electrical Characteristics

Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.

| Symbol | Parameter | Conditions | Min. | Typ. | Max. | Unit |
|--|------------------------------------|---|------|------|------|---------------|
| Off Characteristics | | | | | | |
| BV_{DSS} | Drain-Source Breakdown Voltage | $V_{GS} = 0\text{ V}, I_D = 250\ \mu\text{A}$ | 100 | | | V |
| I_{DSS} | Zero Gate Voltage Drain Current | $V_{DS} = 100\text{ V}, V_{GS} = 0\text{ V}$ | | | 1 | μA |
| | | $V_{DS} = 20\text{ V}, V_{GS} = 0\text{ V}$ | | | 10 | nA |
| I_{GSSF} | Gate-Body Leakage, Forward | $V_{GS} = 20\text{ V}, V_{DS} = 0\text{ V}$ | | | 50 | nA |
| I_{GSSR} | Gate-Body Leakage, Reverse | $V_{GS} = -20\text{ V}, V_{DS} = 0\text{ V}$ | | | -50 | nA |
| On Characteristics⁽²⁾ | | | | | | |
| $V_{GS(th)}$ | Gate Threshold Voltage | $V_{DS} = V_{GS}, I_D = 1\text{ mA}$ | 0.8 | 1.7 | 2.0 | V |
| $R_{DS(on)}$ | Static Drain-Source On-Resistance | $V_{GS} = 10\text{ V}, I_D = 0.17\text{ A}$ | | 1.39 | 6 | Ω |
| | | $V_{GS} = 4.5\text{ V}, I_D = 0.17\text{ A}$ | | 1.48 | 10 | |
| g_{FS} | Forward Transconductance | $V_{DS} = 10\text{ V}, I_D = 0.17\text{ A}$ | 80 | | | mS |
| V_{SD} | Drain-Source Diode Forward Voltage | $V_{GS} = 0\text{ V}, I_S = 0.34\text{ A}$ | | 0.81 | 1.30 | V |
| Dynamic Characteristics | | | | | | |
| C_{iss} | Input Capacitance | $V_{DS} = 25\text{ V}, V_{GS} = 0\text{ V},$ $f = 1.0\text{ MHz}$ | | 71 | | pF |
| C_{oss} | Output Capacitance | | | 6.6 | | pF |
| C_{riss} | Reverse Transfer Capacitance | | | 2.74 | | pF |
| Switching Characteristics⁽²⁾ | | | | | | |
| t_r | Turn-On Rise Time | $V_{DD} = 30\text{ V}, I_D = 0.28\text{ A},$ $V_{GS} = 10\text{ V}, R_{GEN} = 6\ \Omega$ | | 1.24 | 8 | ns |
| t_f | Turn-Off Fall Time | | | 5.73 | 16 | ns |
| $t_{d(on)}$ | Turn-On Delay | | | 2.94 | 8 | ns |
| $t_{d(off)}$ | Turn-Off Delay | | | 8.4 | 13 | ns |

Note:

2. Pulse test: pulse width $\leq 300\ \mu\text{s}$, duty cycle $\leq 2.0\%$.

Typical Performance Characteristics

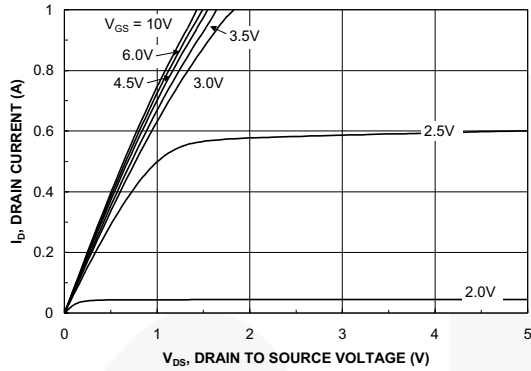


Figure 1. On-Region Characteristics

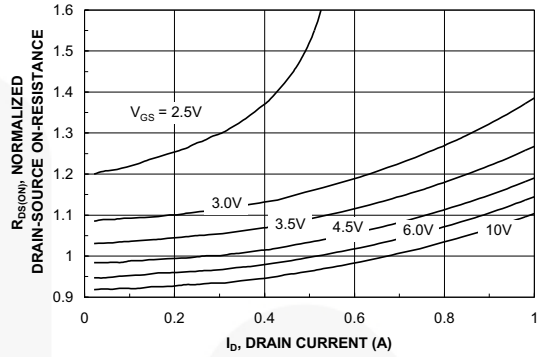


Figure 2. On-Resistance Variation with Drain Current and Gate Voltage

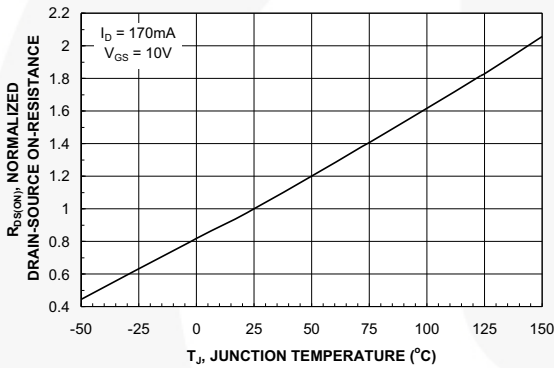


Figure 3. On-Resistance Variation with Temperature

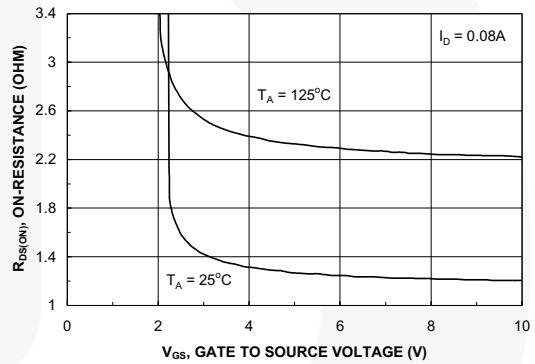


Figure 4. On-Resistance Variation with Gate-to-Source Voltage

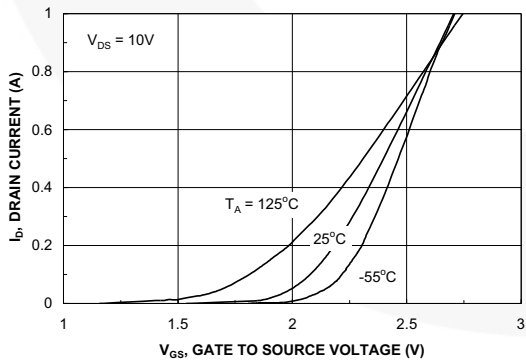


Figure 5. Transfer Characteristics

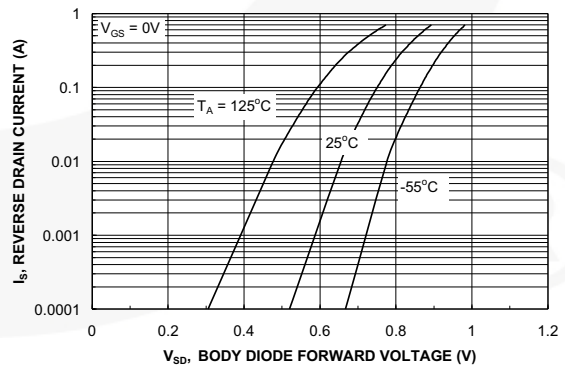


Figure 6. Body Diode Forward Voltage Variation with Source Current and Temperature

Typical Performance Characteristics (Continued)

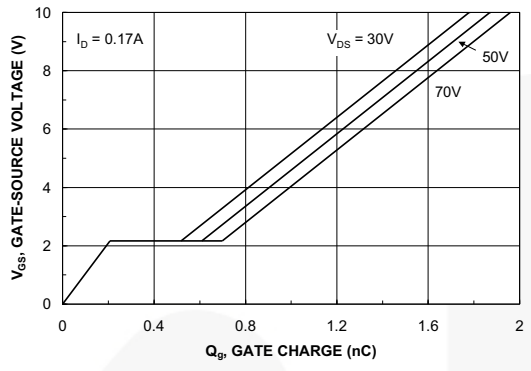


Figure 7. Gate Charge Characteristics

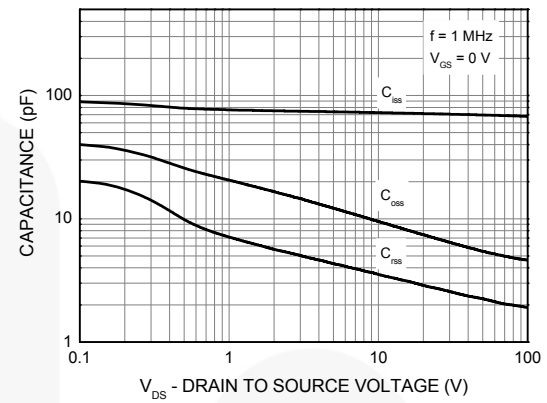
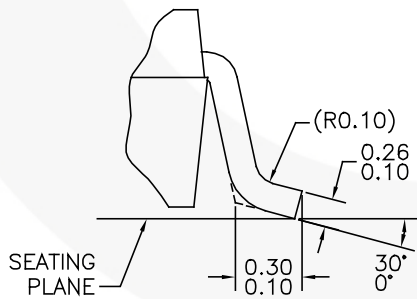
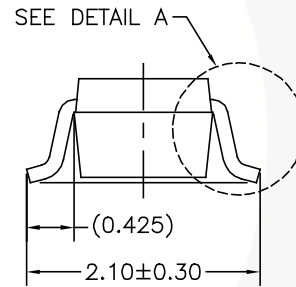
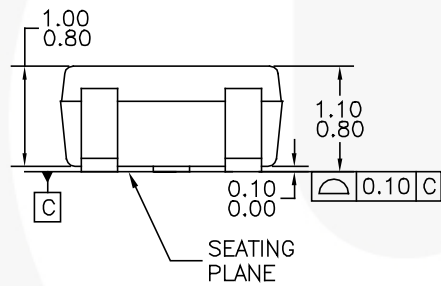
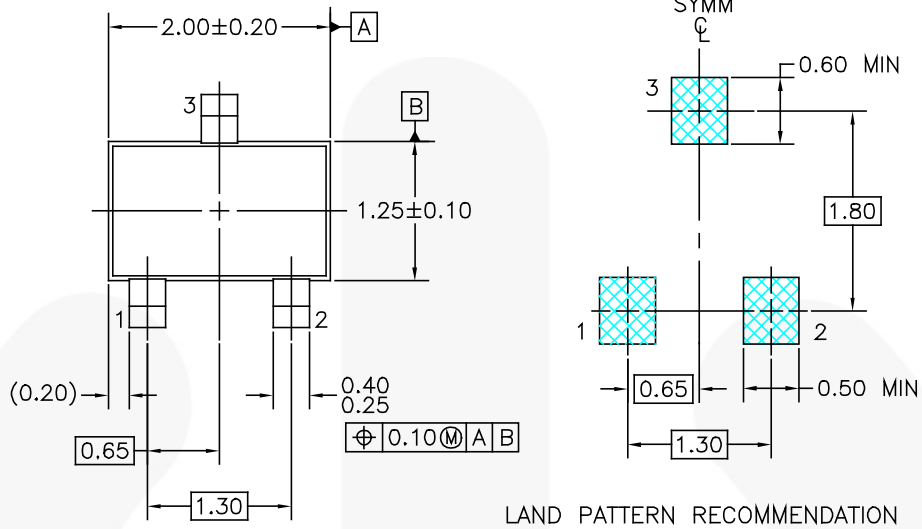


Figure 8. Capacitance

Physical Dimensions



DETAIL A
SCALE: 2X

NOTES: UNLESS OTHERWISE SPECIFIED

- A) THIS PACKAGE CONFORMS TO EIAJ SC-70.
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSIONS DO NOT INCLUDE BURRS OR MOLD FLASH.

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Figure 9. 3-LEAD, SC70, EIAJ SC-70, 1.25MM WIDE





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